## NSN 5961-01-235-3281

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-235-3281
Inclosure Material:
Metal
Overall Length:
Between 0.240 inches and 0.260 inches
Terminal Length:
Between 1.500 inches and 1.750 inches
Overall Diameter:
Between 0.335 inches and 0.370 inches
Function For Which Designed:
Amplifier
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
150.0 collector to base voltage/static/emitter open and 150.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
300.00 milliamperes source cutoff current
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector preset
Transfer Ratio:
20.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-s-19500/366 government specification
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

## **NSN 5961-01-235-3281** Transistor - Page 2 of 2



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